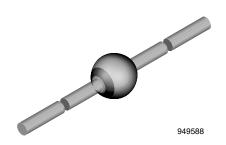
# BYM36A, BYM36B, BYM36C, BYM36D, BYM36E

Vishay Semiconductors



# **Fast Avalanche Sinterglass Diode**



#### **MECHANICAL DATA**

Case: SOD-64

Terminals: plated axial leads, solderable per MIL-STD-750,

method 2026

Polarity: color band denotes cathode end

Mounting position: any Weight: approx. 858 mg

#### **FEATURES**

- · Glass passivated
- · Hermetically sealed package
- Very low switching losses
- · Low reverse current
- High reverse voltage
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition







#### HALOGEN FREE

### **APPLICATIONS**

- Switched mode power supplies
- High-frequency inverter circuits

PARTS TABLE			
PART	TYPE DIFFERENTIATION	PACKAGE	
BYM36A	V <sub>R</sub> = 200 V; I <sub>FAV</sub> = 3 A	SOD-64	
BYM36B	V <sub>R</sub> = 400 V; I <sub>FAV</sub> = 3 A	SOD-64	
BYM36C	V <sub>R</sub> = 600 V; I <sub>FAV</sub> = 3 A	SOD-64	
BYM36D	V <sub>R</sub> = 800 V; I <sub>FAV</sub> = 2.9 A	SOD-64	
BYM36E	V <sub>R</sub> = 1000 V; I <sub>FAV</sub> = 2.9 A	SOD-64	

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
Reverse voltage = repetitive peak reverse voltage	See electrical characteristics	BYM36A	$V_R = V_{RRM}$	200	V
		BYM36B	$V_R = V_{RRM}$	400	V
		BYM36C	$V_R = V_{RRM}$	600	V
		BYM36D	$V_R = V_{RRM}$	800	V
		BYM36E	$V_R = V_{RRM}$	1000	V
Peak forward surge current	t <sub>p</sub> = 10 ms, half sine wave		I <sub>FSM</sub>	65	Α
Average forward current		BYM36A	I <sub>FAV</sub>	3	Α
		BYM36B	I <sub>FAV</sub>	3	Α
		BYM36C	I <sub>FAV</sub>	3	Α
		BYM36D	I <sub>FAV</sub>	2.9	Α
		BYM36E	I <sub>FAV</sub>	2.9	Α
Non repetitive reverse avalanche energy	I <sub>(BR)R</sub> = 1 A, inductive load		E <sub>R</sub>	20	mJ
Junction and storage temperature range			$T_j = T_{stg}$	- 55 to + 175	°C

MAXIMUM THERMAL RESISTANCE (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Junction ambient	Lead length I = 10 mm, T <sub>L</sub> = constant	$R_{thJA}$	25	K/W
Junction ambient	On PC board with spacing 25 mm	$R_{thJA}$	70	K/W



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		BYM36A	$V_{F}$	-	-	1.6	V
		BYM36B	$V_{F}$	-	-	1.6	V
	I <sub>F</sub> = 3 A	ВҮМ36С	$V_{F}$	-	-	1.6	V
		BYM36D	$V_{F}$	-	-	1.78	V
Earword voltage		BYM36E	$V_{F}$	-	-	1.78	V
Forward voltage	I <sub>F</sub> = 3 A, T <sub>j</sub> = 175 °C	BYM36A	$V_{F}$	-	-	1.22	V
		BYM36B	$V_{F}$	-	-	1.22	V
		BYM36C	$V_{F}$	-	-	1.22	V
		BYM36D	$V_{F}$	-	-	1.28	V
		BYM36E	$V_{F}$	-	-	1.28	V
Reverse current	$V_R = V_{RRM}$		I <sub>R</sub>	-	-	5	μA
neverse current	$V_R = V_{RRM}, T_j = 150 ^{\circ}\text{C}$		I <sub>R</sub>	-	-	100	μΑ
	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, i <sub>R</sub> = 0.25 A	BYM36A	t <sub>rr</sub>	-	-	100	ns
		BYM36B	t <sub>rr</sub>	-	-	100	ns
Reverse recovery time		BYM36C	t <sub>rr</sub>	-	-	100	ns
		BYM36D	t <sub>rr</sub>	-	-	150	ns
		BYM36E	t <sub>rr</sub>	-	-	150	ns
	I <sub>R</sub> = 100 μA	BYM36A	$V_{(BR)R}$	300	-	-	V
Reverse breakdown voltage		BYM36B	V <sub>(BR)R</sub>	500	-	-	V
		BYM36C	V <sub>(BR)R</sub>	700	-	-	V
		BYM36D	V <sub>(BR)R</sub>	900	-	-	V
		BYM36E	V <sub>(BR)R</sub>	1100	-	-	V

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

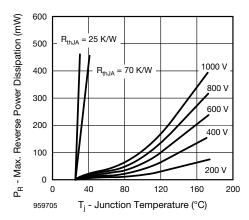


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature

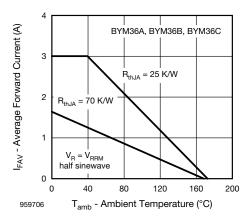


Fig. 2 - Max. Average Forward Current vs. Ambient Temperature

# BYM36A, BYM36B, BYM36C, BYM36D, BYM36E

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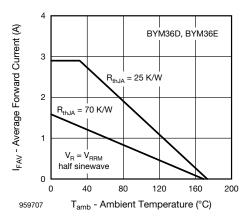
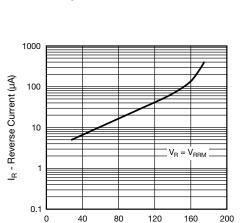


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature



T<sub>i</sub> - Junction Temperature (°C) Fig. 4 - Max. Reverse Current vs. Junction Temperature

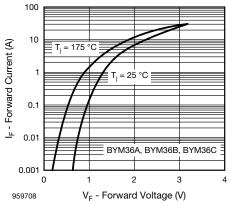


Fig. 5 - Max. Forward Current vs. Forward Voltage

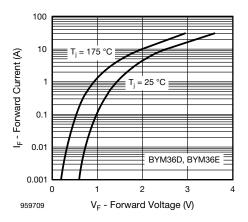


Fig. 6 - Max. Forward Current vs. Forward Voltage

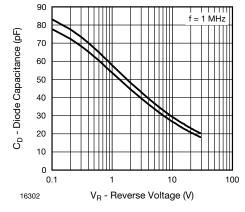


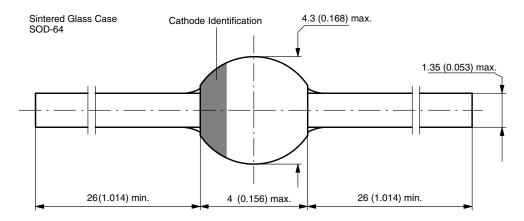
Fig. 7 - Diode Capacitance vs. Reverse Voltage

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# BYM36A, BYM36B, BYM36C, BYM36D, BYM36E

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#### PACKAGE DIMENSIONS in millimeters (inches): SOD-64



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